

INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

Docket Number (Optional)

12486A (BU9-99-064)

Application Number

Unassigned

Applicant(s)

Charles Thomas Black, et al.

Filing Date

Herewith

Group Art Unit

Unassigned

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
MC		5,624,864	4/29/97	Arita et al.			
MC		5,658,820	8/19/97	Chung			
MC		5,702,970	12/30/97	Choi			
MC		5,716,875	2/10/98	Jones, Jr. et al.			
MC		5,736,422	4/7/98	Lee et al.			
MC		5,784,310	7/21/98	Cuchiario et al.			
MC		5,812,442	9/22/98	Yoo			
MC		5,821,005	10/13/98	Kijima et al.			
MC		5,822,239	10/13/98	Ishihara et al.			

JCB57 U.S. PTO
09/927694
08/10/2001

FOREIGN PATENT DOCUMENTS

	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
							YES	NO
MC		EP O 883 167 A2	12/9/98	EPO				

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

MC	J. R. McBride, et al., "Growth and Characterization of Relatively Sputtered Thin-Film Platinum Oxides," J. Appl. Phys., Vol. 69, No. 3, pp. 1596-1604 (1991).
	J.-H. Joo, et al., "Improvement of Leakage Currents of Pt/(Ba, Sr) TiO3/Pt Capacitors," Appl. Phys. Lett., Vol. 70, No. 22, pp. 3053-3055 (1997).
	Y. Abe, et al., "Preparation of Oxygen-Containing Pt and Pt Oxide Thin Films by Reactive Sputtering and Their Characterization," Jpn. J. Appl. Phys., Vol. 37, No. 8, pp. 4482-4480 (1998).
MC	Y. Tsunemine, et al., "A Manufacturable Integration Technology of Sputter-BST Capacitor With a Newly Proposed Thick Pt Electrode," Paper 30-3, IEDM (December 1998).

EXAMINER

Mano Guerrero

DATE CONSIDERED

1-10-03

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.